

High Voltage Switching Diode

BAS21H

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_{R}	250	V
Repetitive Peak Reverse Voltage	V_{RRM}	250	V
Peak Forward Current	I _F	200	mA
Repetitive Peak Forward Current	I _{FRM}	500	mA
Non-Repetitive Peak Forward Surge Current, 60 Hz	I _{FSM(surge)}	2.5	Α
Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^{\circ}C$ prior to surge) $t = 1 \ \mu s$ $t = 10 \ \mu s$ $t = 100 \ \mu s$ $t = 1 \ ms$ $t = 1 \ s$	IFSM	20 20 10 4 1	A

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C	P_{D}	200	mW
Derate above 25°C		1.57	mW/°C
Thermal Resistance, Junction-to-Ambient Junction-to-Lead Junction-to-Top	R _{θJA} R _{θJL} R _{θJT}	635 240 436	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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1. FR-5 Minimum Pad

HIGH VOLTAGE SWITCHING DIODE





SOD-323 CASE 477 STYLE 1

MARKING DIAGRAM



JS = Device Code M = Date Code*

■ = Pb-Free Package (Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

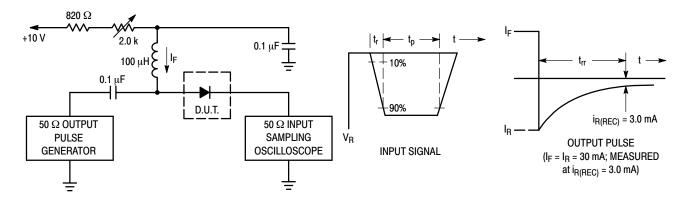
Device	Package	Shipping [†]
BAS21HT1G, NSVBAS21HT1G	SOD-323 (Pb-Free)	3000 / Tape & Reel
BAS21HT3G, NSVBAS21HT3G	SOD-323 (Pb-Free)	10000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure. BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	
Reverse Voltage Leakage Current $(V_R = 200 \text{ Vdc})$ $(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I _R	- -	0.1 100	μAdc
Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _(BR)	250	-	Vdc
Forward Voltage (I _F = 100 mAdc) (I _F = 200 mAdc)	V _F	- -	1000 1250	mV
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	_	5.0	pF
Reverse Recovery Time (I _F = I _R = 30 mAdc, R _L = 100 Ω)	t _{rr}	-	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 $k\Omega$ variable resistor adjusted for a Forward Current (I_F) of 30 mA.

- 2. Input pulse is adjusted so I_{R(peak)} is equal to 30 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

BAS21H

TYPICAL CHARACTERISTICS

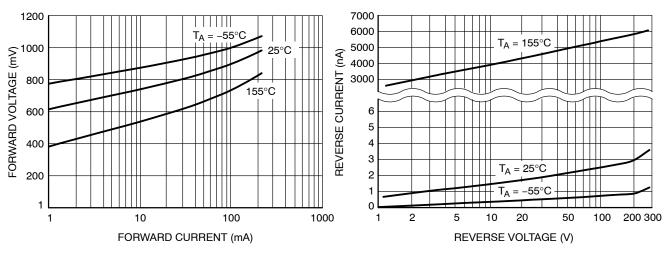


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

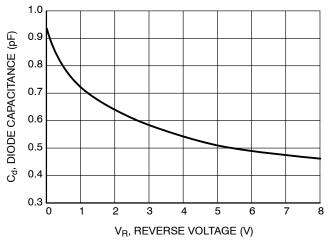


Figure 4. Diode Capacitance

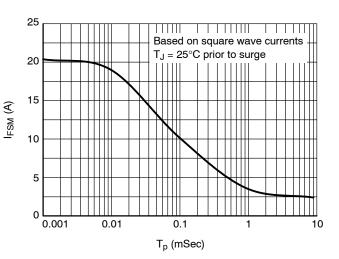


Figure 5. Maximum Non-repetitive Peak Forward Current as a Function of Pulse Duration, Typical Values

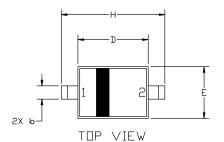






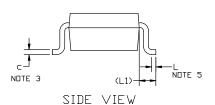
SOD-323 1.70x1.25x0.85 **CASE 477 ISSUE K**

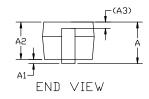
DATE 11 MAR 2024



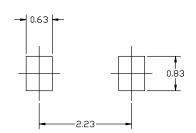
NOTES:

- 1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH 3. SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 DIMENSION L IS MEASURE FROM END OF RADIUS.





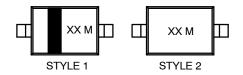
DIM	MILLIMETERS			
ואונע	MIN.	N□M.	MAX.	
Α	0.80	0.90	1.00	
A1	0.00	0.05	0.10	
A2	0.75	0.85	0.95	
А3	0.15 (REF)			
b	0.25	0.32	0.4	
C	0.09	0.12	0.18	
D	1.60	1.70	1.80	
Ε	1.15	1.25	1.35	
Н	2.30	2.50	2.70	
L	0.08			
L1	0.40 (REF)			



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques
Reference manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 2: NO POLARITY PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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DESCRIPTION:	SOD-323 1.70x1.25x0.85		PAGE 1 OF 1	

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